

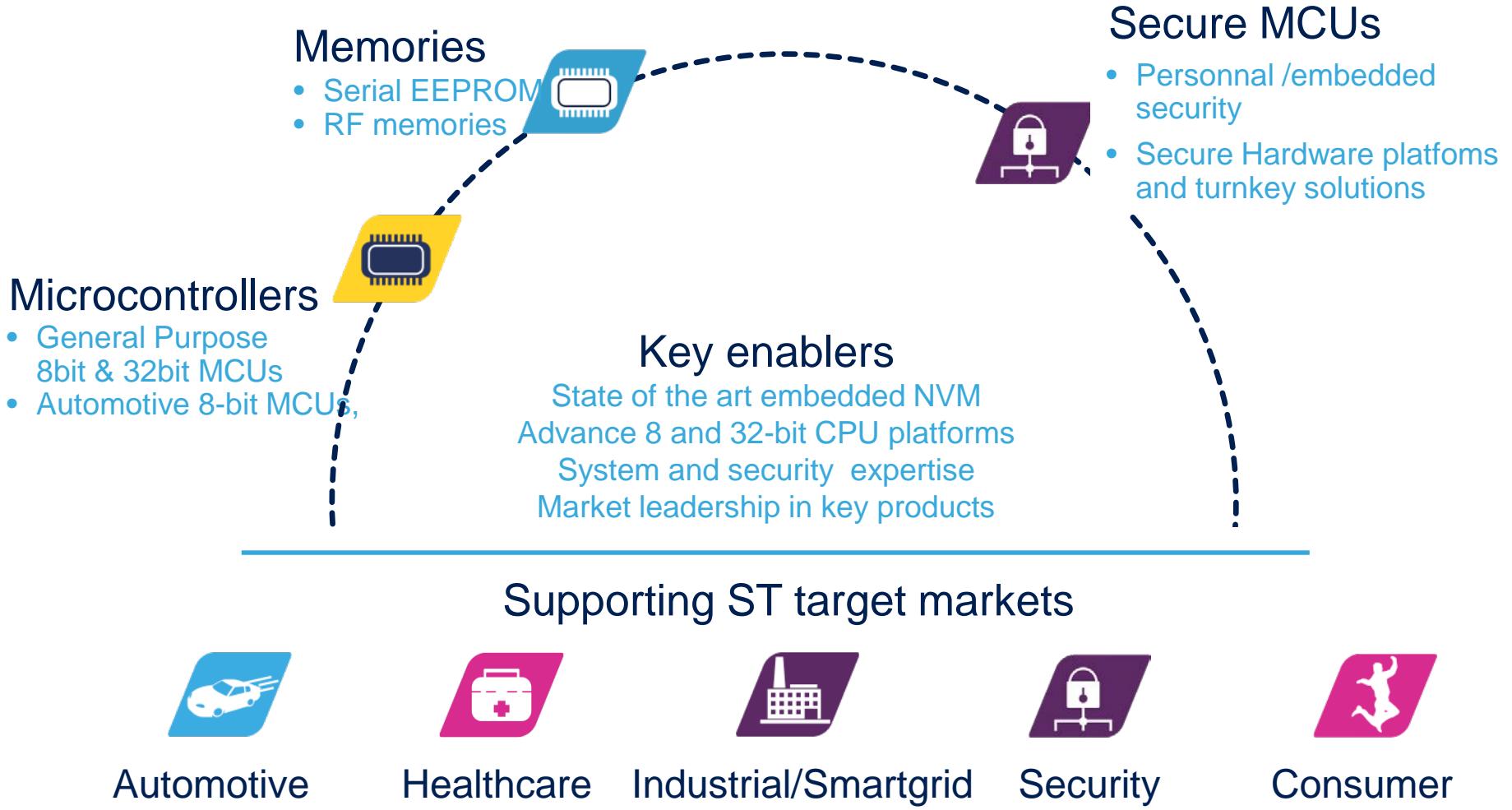


MDG-MMS group Stage proposals on e-NVM

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Secure MCUs Perimeter

3

Market

Banking



Pay TV



Personal Security

Mobile NFC / SIM & M2M



Embedded Security

Identity



Transport



Computer Consumer Security



Enablers

eNVM Technology



Advanced security



Contactless performance



Software & Turn-key solutions

GP and Secure Micro e-NVM Demand

4

- Performances

- High reading speed (10ns – 30ns of access time)
- Low consumption for ULP of RF applications (Stand-By, Reading, Modify)
- Cycling capability above 500Kc at hot temperature (105°C)
- More than 15 years of retention



- Low cost process and design

- Reduced periphery area
- High density bit cell for Code Storage purposes
- Optimized analog design
- Easy integration of Memory Process module

Stage Proposals

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- 1. Study and implementation of static and dynamic I/R Drop simulation flow for complex NVM IPs in advanced technology nodes.
- 2. Montecarlo simulation on e-NVM Read-path for high accuracy analysis and access time characterization.
- 3. Ultra low power and low area analog design of e-NVM building blocks in FDSOI technologies.

Maximum number of selected Interns will be 2